

METHOD AND CIRCUIT FOR DETECTING MOVEMENTS THROUGH MICRO-ELECTRIC-MECHANICAL SENSORS, COMPENSATING PARASITIC CAPACITANCES AND SPURIOUS MOVEMENTS

BACKGROUND OF THE INVENTION

5 Field of the Invention

The present invention relates to a method and a circuit for detecting movements through micro-electric-mechanical sensors, compensating parasitic capacitances and spurious movements.

Description of the Related Art

10 As is known, the use of micro-electric-mechanical sensors, or MEMS sensors, with differential capacitive unbalance has been proposed for forming, for example, linear or rotational accelerometers and pressure sensors.

In particular, MEMS sensors of the indicated type comprise a fixed body (stator) and a moving mass, generally made of suitably doped semiconductor material,
15 connected to each other through elastic elements (springs) and restrained so that, with respect to the stator, the moving mass has predetermined translational and rotational degrees of freedom. Moreover, the stator and the moving mass have a plurality of fixed and, respectively, moving arms, interleaved to each other. In practice, each fixed arm is arranged between a pair of moving arms, so as to form a pair of capacitors having a common terminal and a
20 capacitance which is a function of the relative position of the arms, that is on the relative position of the moving mass with respect to the stator. When the sensor is stressed, the moving mass moves and the capacitance of the capacitors is unbalanced.

Depending on the type of structure and relative movement allowed between the moving mass and the stator, it is possible to manufacture MEMS sensors of a linear or
25 rotational type, with variable interspace (distance between each moving arm and the respective

fixed arms) and/or with variable facing area (variation of the reciprocal facing area between the moving arms and the respective fixed arms).

In all mentioned cases, reading by the sensor (that is the detection of an electric quantity representing the variation of the capacitance of the capacitors) leads to problems due
5 to the presence of parasitic capacitances (pad and substrate capacitances).

To overcome this problem, a method and a circuit for reading MEMS sensors have been proposed in “A Three-Axis Micromachined Accelerometer with a CMOS Position-Sense Interface and Digital Offset-Trim Electronics” by M. Lemkin, B. Boser, IEEE Journal of Solid-State Circuits, Vol. 34, N. 4, Pages 456-468.

10 In the mentioned article, in particular, reference is made to a sensor MEMS 1 of linear type, illustrated, for greater clarity, in Figures 1 and 2; however, the following description applies to MEMS sensors of any type.

In detail, the sensor 1 comprises a stator 2 and a moving mass 3, connected to each other by springs 4 so that the moving mass 3 can translate parallel to a first reference axis
15 X, while it is substantially fixed with respect to a second and a third reference axis Y, Z. The sensor 1 is also symmetrical with respect to a longitudinal axis parallel to the first reference axis X.

The a stator 2 and the moving mass 3 are provided with a plurality of first and second fixed arms 5', 5" and, respectively, with a plurality of moving arms 6, extending
20 substantially parallel to the plane Y-Z.

As shown in detail in Figure 2, each moving arm 6 is arranged between two respective fixed arms 5', 5", partially facing them. Consequently, the moving arm 6 forms with the two fixed arms 5', 5" a first and, respectively, a second detection capacitor 8, 9 with parallel flat faces. In particular, the area of the plates of the detection capacitors 8, 9 is equal
25 to the facing area A of the moving arms 6 and of the fixed arms 5', 5". In particular, the facing area A is substantially a rectangle with sides Ly, Lz.

The first and the second detection capacitor 8, 9 have a first and, respectively, a second detection capacitance Ca, Cb, given by the equations:

$$Ca = \epsilon \frac{A}{X1} \quad (1)$$

$$Cb = \epsilon \frac{A}{X2} \quad (2)$$

where X1, X2 are the distances between the moving arm 6 and the first and, respectively, the second fixed arms 5', 5" of Figure 2 and ϵ is the dielectric constant of the air.

5 In the sensor 1, all the detection capacitances Ca formed between the moving arms 6 and the first fixed arms 5' are parallel-connected; similarly all the detection capacitances Cb formed between the moving arms 6 and the second fixed arms 5" are parallel-connected. Consequently, altogether two capacitances are present between the stator 3 and the
10 moving mass 4, equal to $C1 = N*Ca$ and, respectively, to $C2 = N*Cb$, with N number of moving arms 6 of the sensor 1. If we define as the common detection capacitance Cs of the sensor 1 the value of the capacitances C1, C2 at rest, we have:

$$Cs = C1 = C2 \quad (3)$$

15 After a movement of the moving arm 4 purely along the axis X, the detection capacitances C1, C2 present variations with an opposite sign and with a same absolute value, and equal to a capacitive unbalance ΔCs .

Figure 3, showing a simplified electric equivalent of the sensor MEMS 1, shows a detection circuit 10, of the type described in the article mentioned.

In particular, the sensor MEMS 1 is schematized by a first and a second equivalent detection capacitor 11, 12, having first terminals connected to a first and,
20 respectively, a second detection node 13, 14 and second terminals connected to a common node 15. Moreover, the first and the second equivalent detection capacitor 11, 12 have capacitances equal to the first and, respectively, to the second detection capacitance C1, C2. The first and the second detection node 13, 14 are connected to all the first arms 5' and, respectively, to all the second arms 5" of the stator 3, while the common node 15 is connected
25 to the moving mass 4 and therefore to the moving arms 6. Moreover, in Figure 3 the parasitic

capacitances of the sensor MEMS 1 are schematized by parasitic capacitors 17, 18 connected between the detection nodes 13, respectively 14, and the mass.

The detection circuit 10 comprises a detection operational amplifier 20 in a charge integration configuration and a feedback stage 21.

5 In detail, the detection operational amplifier 20, having a completely differential topology, has an inverting input connected to the first detection node 13 and a non-inverting input connected to the second detection node 14; and it has a non-inverting output 20a and an inverting output 20b between which is an output voltage V_o . Moreover, a first and a second integration capacitor 22, 23, having a same integration capacitance C_i , are connected
10 one between the inverting input and the non-inverting output 20a and the other between the non-inverting input and the inverting output 20b of the detection operational amplifier 20.

The feedback stage 21 comprises an amplifying circuit 25 and a first and a second feedback capacitor 26, 27, having first terminals connected to an output 25a of the amplifying circuit 25 and second terminals connected to the first and, respectively, to the
15 second detection node 13, 14. The amplifying circuit 25, the structure and operation whereof are described in detail in the mentioned article, is a switched-capacitors circuit having a first and a second differential input 25b, 25c, connected to the inverting input and, respectively, to the non-inverting input of the detection operational amplifier 20, and a reference input, connected to a voltage generator 29 that supplies a first reference voltage V_{r1} . In practice, the
20 amplifying circuit 25, in a first operative step, detects the voltage between the differential inputs 25b, 25c, determines their mean value and, in a second step, outputs a feedback voltage V_{FB} proportional to the difference between this mean value and the first reference voltage V_{r1} .

The reading by the sensor MEMS 1 is performed supplying the moving mass 4 with a detection voltage V_s with square wave. The feedback stage 20 intervenes so as to
25 maintain the first and the second detection node 13, 14 at a constant voltage. In particular, the feedback voltage V_{FB} supplied by the amplifying circuit 25 is a square wave in phase-opposition with respect to the detection voltage V_s . In this way, the parasitic capacitors 17, 18 have no influence, since they are maintained at a constant voltage and do not absorb any charge, thereby eliminating the error due to the parasitic capacitances of the sensor MEMS 1.

The output voltage V_o between the outputs 20a, 20b of the detection operational amplifier 20 is given by the equation:

$$V_o = 2Vs \frac{\Delta C_s}{C_i} \quad (4)$$

wherein, as mentioned previously, ΔC_s is the capacitive unbalance of the sensor MEMS 1, that
5 is the capacitance variation of the first and of the second equivalent detection capacitor 11, 12 after movements of the moving mass 4.

The precision of the detection circuit described, however, is limited by another problem, caused by spurious movement, that are not consistent with the allowed degree of freedom and due to the non-ideal nature of the mechanical restraints.

10 In greater detail, supposing for simplicity's sake that the distances X_1, X_2 are initially the same and equal to a rest distance X_0 , from equations (1)-(3) it results that the component ΔC_{sx} of the capacitive unbalance ΔC_s according to the first reference axis X is given by the equation:

$$\Delta C_{sx} = -\frac{dC_s}{dX} \Delta X = \frac{\varepsilon A}{X_0^2} \Delta X = \frac{C_s}{X_0} \Delta X \quad (5)$$

15 where ΔX is the movement of the moving mass 4 along the first reference axis X.

In presence of a spurious movement ΔY parallel to the second reference axis Y, the capacitive unbalance ΔC_s has a component ΔC_{sy} given by the equation:

$$\Delta C_{sy} = -\frac{dC_s}{dY} \Delta Y = -\frac{\varepsilon L_y}{X_0} \Delta Y = -\frac{C_s}{L_y} \Delta Y \quad (6)$$

Any spurious movements ΔZ along the third reference axis Z are instead
20 compensated by virtue of the axial symmetry of the sensor MEMS 1.

While the unbalance introduced by the movement ΔX is of a differential type and is itself suitable to be detected by the detection operational amplifier 20, which has a completely differential topology, the movement ΔY introduces a notable common mode

variation of the common detection capacitance C_s , as it causes a variation of the facing area A (Figure 2).

Since the output voltage V_o is directly proportional to the capacitive unbalance ΔC_s , which in turn is directly proportional to the common detection capacitance C_s , the 5 common mode variation due to the movement ΔY introduces a significant detection error.

BRIEF SUMMARY OF THE INVENTION

An embodiment of the present invention overcomes the problems described.

According to various embodiment of the present invention, methods for compensating parasitic movements in a micro-electric-mechanical sensor, a method for 10 detecting movements through micro-electric-mechanical sensors and circuits for detection of movements and compensation of spurious movements are provided.

The method for detecting movements through a micro-electric-mechanical sensor having a fixed body and a moving mass, includes forming first and second detection capacitors connected to a common node and to first and second detection nodes respectively, 15 and having a common detection capacitance at rest and a capacitive unbalance in case of a movement. The method includes the steps of: feeding the common node with a constant detection voltage of predetermined duration; generating a feedback voltage to maintain the first and second detection nodes at a constant common mode voltage; generating a compensation electric quantity, inversely proportional to the common detection capacitance at least in one 20 predetermined range; supplying the compensating electric quantity to the common node; and detecting an output quantity related to the capacitive unbalance.

A device according to an embodiment of the invention includes an electro-mechanical sensor having a movable mass and a fixed body, configured to detect motion in a first axis and including first and second detection capacitors formed between the movable mass 25 and the fixed body, the movable mass being a common node of the first and second capacitors, a first circuit, configured to compare capacitances of the first and second capacitors and provide an output voltage proportionate with a difference of capacitances thereof, and a second

circuit, configured to supply a compensation voltage to the common node, inversely proportionate to a common capacitance of the sensor.

According to another embodiment of the invention, the device also includes a feedback network having a feedback voltage proportionate with the common capacitance of the sensor, an input coupled with the feedback network, a memory configured to periodically store the level of the feedback voltage, an amplifier configured to receive the stored feedback voltage level during intervals between the periods of storage in the memory and to output the compensation voltage, and an output coupling the amplifier output with the common node.

BRIEF DESCRIPTION OF THE SEVERAL VIEWS OF THE DRAWINGS

For a better understanding of the invention, two embodiments are now described, purely as non-limitative examples, with reference to the enclosed drawings, wherein:

Figure 1 is a perspective view of a micro-electric-mechanical sensor of a known type;

Figure 2 is an enlarged perspective view of a detail of the sensor in Figure 1;

Figure 3 is a simplified circuit diagram of a detection circuit for a micro-electric-mechanical sensor, of a known type;

Figure 4 is a simplified circuit diagram of a detection circuit for a micro-electric-mechanical sensor according to a first embodiment of the present invention;

Figure 5 is a graph of the quantities present in the circuit in Figure 4; and

Figure 6 is a simplified circuit diagram of a detection circuit for a micro-electric-mechanical sensor according to a second embodiment of the present invention.

DETAILED DESCRIPTION OF THE INVENTION

Figure 4, in which parts similar to those already shown are indicated with the same reference numbers, illustrates a detection circuit 30 which differs from the detection circuit 10 in Figure 3 by comprising a compensating stage 31. In particular, the detection circuit 30 is connected to the sensor MEMS 1 (here schematized by the first and the second

equivalent detection capacitor 11, 12, connected one between the first detection node 13 and the common node 15 and the other between the second detection node 14 and the common node 15) and comprises the detection operational amplifier 20 and the feedback stage 21. Moreover, a signal generator 60 is connected to a first input 61a of a selector 61, of a known type, having a second input 61b and an output 61c. The output 61c is connected to the common node 15.

As already mentioned, the detection operational amplifier 20, having a completely differential topology, operates as a charge integrator and has an inverting input connected to the first detection node 13 and a non-inverting input connected to the second detection node 14. The feedback stage comprises the amplifying circuit 25, having the differential inputs 25b, 25c connected to the inverting and, respectively, the non-inverting inputs of the detection operational amplifier 20; and the first and the second feedback capacitor 26, 27 connected one between the output 25a of the amplifying circuit 25 and the first detection node 13 and the other between the output 25a of the amplifying circuit 25 and the second detection node 14.

The compensating stage 31 has an input, connected to the output 25a of the amplifying circuit 25, and an output 31a, connected to the second input 61b of the selector 61 and supplying a compensation voltage V_c , linked to the common detection capacitance C_s of the sensor MEMS 1 approximately by an inverse proportional function, as explained in detail below.

The compensating stage 31 comprises a memory capacitor 32, an uncoupling stage 33 and a compensating operational amplifier 35 with negative gain.

The memory capacitor 32 has a first terminal connected to ground and a second terminal connected to the output 25a of the amplifying circuit 25 via a first switch 36 and to the uncoupling stage 33 via a second switch 37, controlled in counterphase with respect to the first switch 36.

The uncoupling stage 33 is preferably formed by an operational amplifier in a follower configuration, that is having a non-inverting input connected to the second switch 37 and an inverting input directly connected to the output.

The compensating operational amplifier 35, configured as an inverting amplifier, has an inverting terminal connected to the output of the uncoupling stage 33 through an input resistor 40, a non-inverting terminal connected to ground and an output forming the output of the compensating stage 31 and supplying the compensating voltage V_c ; moreover, 5 the output and the inverting terminal of the compensating operational amplifier 35 are connected to each other through a feedback resistor 41.

It will now be shown that the relationship between the common detection capacitance C_s is linked, in a first approximation, to the compensating voltage V_c by a relationship of inverse proportionality.

10 In fact, when the moving mass 4 is supplied with the detection voltage V_s , the feedback voltage V_{FB} supplied to the amplifying circuit 25 assumes a value that is directly proportional to the overall detection capacitance C_s , like the output voltage V_o , and may be expressed as follows:

$$V_{FB} = K_1 V_s C_s \quad (7)$$

15 where K_1 is a first constant. Note also that the amplitude of the detection voltage V_s is constant.

In two successive steps, the feedback voltage V_{FB} is stored and then transferred to the compensating operational amplifier 35 through the uncoupling stage 33.

20 Therefore, indicating with G the absolute value of the gain of the compensating operational amplifier 35 and with V_{c0} the value of the compensating voltage V_c in the absence of input voltage, we have:

$$V_c = V_{c0} - G V_{FB} = V_{c0} - G K_1 V_s C_s \quad (8)$$

Since the variations of the common detection capacitance C_s due to the spurious movements ΔY are in the range of femtoFarad, in a predetermined neighborhood I of 25 a rest value C_{s0} of the common detection capacitance C_s the equation (8) is a first-degree approximation of a relationship of inverse proportionality given by (see Figure 5):

$$V_c' = K_2 / C_s \quad (9)$$

where V_c' is an ideal compensating voltage and K_2 is a second constant.

Therefore, linearising the plot of the compensating voltage V_c in the neighborhood I , a negligible error is made and the following relationship may correctly be considered valid:

5

$$V_c = V_c' = K_2 / C_s \quad (10)$$

In practice, a detection cycle of the sensor MEMS 1 is carried out as follows.

Initially the selector 61 supplies, to the moving mass 4 (represented in Figure 4 by the common node 15), the constant voltage V_s . According to the detailed description given in the article mentioned, in this condition the amplifying circuit 25 of the feedback stage 21 10 outputs a value of the feedback voltage V_{FB} such as to maintain constant the common mode voltage between the first and the second detection node 13, 14 (that is the mean between the voltages present on these nodes); moreover, since the detection operational amplifier 20 substantially maintains at zero the voltage existing between its inputs, the first and the second detection node 13, 14 are practically virtual ground points.

15

Simultaneously, the first switch 36 of the compensating stage 31 is closed (while the second switch 37 remains open) and the memory capacitor 32 is charged to the feedback voltage V_{FB} , which is thus stored. In this phase, in practice, the common detection capacitance C_s (proportional to the feedback voltage V_{FB}) is detected and then stored so as to be processed later.

20

Later, the switches 36, 37 switch over, so as to connect the memory capacitor 32 to the compensating operational amplifier 35, through the uncoupling stage 33 and the input resistor 40. Therefore, the output 31a of the compensation stage goes to and substantially remains at the compensating voltage V_c indicated by equation (10).

25

Moreover, the selector 61 switches over consequently the compensating voltage V_c is fed to the common node 15 (that is to the moving mass 4). In this phase the output voltage V_o is given by the following relationship:

$$V_o = 2 \frac{K_2}{C_i} \frac{\Delta C_s}{C_s} \quad (11)$$

Since, according to equations (5), (6), the capacitive unbalance ΔCs is given by:

$$\Delta Cs = \Delta Cs_x + \Delta Cs_y = Cs \left(\frac{\Delta X}{X_0} - \frac{\Delta Y}{L_y} \right) \cong Cs \frac{\Delta X}{X_0} \quad (12)$$

the output voltage V_o is substantially independent of the common detection capacitance Cs . In fact, combining the equations (11) and (12), we obtain:

$$V_o = 2 \frac{K_2}{C_i} \frac{\Delta X}{X_0} \quad (13)$$

5

The approximation made in equation (12) is justified because the spurious movements ΔY , due to construction imperfections and completely absent in case of ideal restraints, are much smaller than the movements ΔX , which are instead expected for normal operation of the sensor MEMS 1; moreover, the quantities X_0 and L_y are comparable with
10 each other.

In practice, the dependence of the output voltage V_o on the common detection capacitance Cs which, in a first approximation, follows a direct proportionality relationship, is eliminated by generating a voltage that is inversely proportional to the common detection capacitance Cs and then feeding the voltage thus generated to the moving mass 4.

15 Figure 6, wherein parts similar to those already shown are indicated with the same reference numbers, illustrates a second embodiment of the invention. In particular, a detection circuit 40 comprises the detection operational amplifier 20 and the feedback stage 21, connected to each other and to the sensor MEMS 1 as already described with reference to Figures 3 and 4. Moreover, a compensating stage 41 comprises the memory capacitor 32,
20 connected to the output 25a of the amplifying circuit 25 through the first switch 36, and a compensating operational amplifier 42, having a non-inverting input connected to ground, an inverting input connected through an input resistor 43 to a voltage source 44, supplying a second constant reference voltage V_{r2} , and an output forming an output 41a of the compensating stage 41. Moreover, between the output and the inverting input of the
25 compensating operational amplifier 42 is connected a feedback resistive element 45 with

variable resistance, having a control terminal 45a connected to the memory capacitor 32 through the second switch 37 to receive the stored feedback voltage V_{FB} . The feedback resistive element 45 preferably comprises a transistor MOS operating in a linear zone, the gate terminal of which forms the control terminal 45a.

5 In this case, in practice, the compensating voltage V_c is controlled by modulating the gain value G' through the feedback voltage V_{FB} . Indicating with R_1 and R_2 the resistance of the input resistor 43 and, respectively, of the feedback resistive element 45, the gain G' is given by the equation:

$$G' = -R_2/R_1 \quad (14)$$

10 Moreover:

$$V_c = G' V_{r2} = -G' (R_2/R_1) V_{r2} \quad (15)$$

15 Since, in a first approximation, the resistance of a MOS transistor decreases inversely to the gate-source voltage and vice-versa, the resistance R_2 of the feedback resistive element 45 is inversely proportional to the feedback voltage V_{FB} . Moreover, since, as shown previously, the feedback voltage V_{FB} is directly proportional to the common detection capacitance C_s , from equation (15) derives that, in this case too, the compensating voltage is linked to the common detection capacitance C_s substantially by an inverse proportionality.

From the above it is clear that the invention advantageously allows the elimination of the disturbing effects both of the parasitic capacitances and of the spurious movements caused by mechanical imperfections of MEMS sensors. Consequently, the described detection circuit is much more precise and less prone to errors than traditional detection circuits.

20 Moreover, the method and the circuit described are extremely versatile and may be used for MEMS sensors with differential capacitive unbalance of any type. In particular, as well as linear sensors with variable interspaces, it is possible to use sensors of rotational type and of the type with variable facing area.

Lastly it is clear that modifications and variations may be made to the method and the circuit described, without departing from the scope of the present invention.

In particular, the compensating stage may be implemented in different ways and supply a compensating voltage which represents an approximation different from the one
5 described; the compensating stage could, for example, be implemented by switched-capacitor circuits.

From the foregoing it will be appreciated that, although specific embodiments of the invention have been described herein for purposes of illustration, various modifications may be made without deviating from the spirit and scope of the invention. Accordingly, the
10 invention is not limited except as by the appended claims.